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FDP8030L/FDB8030L

N-Channel Logic Level PowerTrench® MOSFET

General Description

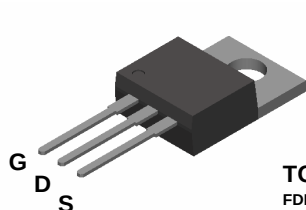
This N-Channel Logic level MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers.

These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable $R_{DS(on)}$ specifications.

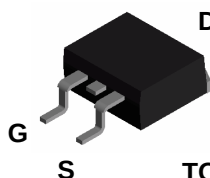
The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

Features

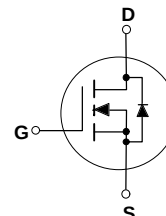
- 80 A, 30 V. $R_{DS(on)} = 0.0035 \Omega @ V_{GS} = 10 \text{ V}$
 $R_{DS(on)} = 0.0045 \Omega @ V_{GS} = 4.5 \text{ V}$
- Critical DC electrical parameters specified at elevated temperature
- Rugged internal source-drain diode can eliminate the need for an external Zener diode transient suppressor
- High performance trench technology for extremely low $R_{DS(on)}$
- 175°C maximum junction temperature rating



TO-220
FDP Series



TO-263AB
FDB Series



Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain-Source Voltage	30	V
V_{GSS}	Gate-Source Voltage	±20	V
I_D	Drain Current – Continuous (Note 1)	80	A
	– Pulsed (Note 1)	300	
P_D	Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	187	W
		1.25	W/°C
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-65 to +175	°C
T_L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	275	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	0.8	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	62.5	°C/W

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Drain-Source Avalanche Ratings (Note 1)

W_{DSS}	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 20\text{ V}, I_D = 80\text{ A}$			1500	mJ
I_{AR}	Maximum Drain-Source Avalanche Current				80	A

Off Characteristics

BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$, Referenced to 25°C		23		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24\text{ V}, V_{GS} = 0\text{ V}$			10	μA
I_{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = 20\text{ V}, V_{DS} = 0\text{ V}$			100	nA
I_{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -20\text{ V}, V_{DS} = 0\text{ V}$			-100	nA

On Characteristics (Note 2)

$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1	1.5	2	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$, Referenced to 25°C		-5		mV/ $^\circ\text{C}$
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10\text{ V}, I_D = 80\text{ A}, T_J = 125^\circ\text{C}$		3.1 4.0	3.5 5.6	m Ω
		$V_{GS} = 4.5\text{ V}, I_D = 70\text{ A}$		3.6	4.5	
$I_{D(on)}$	On-State Drain Current	$V_{GS} = 10\text{ V}, V_{DS} = 10\text{ V}$	60			A
g_{FS}	Forward Transconductance	$V_{DS} = 10\text{ V}, I_D = 80\text{ A}$		170		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}, f = 1.0\text{ MHz}$		10500		pF
C_{oss}	Output Capacitance			2700		pF
C_{rss}	Reverse Transfer Capacitance			1650		pF

Switching Characteristics (Note 2)

$t_{D(on)}$	Turn-On Delay Time	$V_{DD} = 15\text{ V}, I_D = 50\text{ A}, V_{GS} = 4.5\text{ V}, R_{GEN} = 10\text{ }\Omega, R_{GS} = 10\text{ }\Omega$		20	35	ns
t_r	Turn-On Rise Time			185	225	ns
$t_{D(off)}$	Turn-Off Delay Time			160	200	ns
t_f	Turn-Off Fall Time			200	240	ns
Q_g	Total Gate Charge	$V_{DS} = 15\text{ V}, I_D = 80\text{ A}, V_{GS} = 5\text{ V}$		120	170	nC
Q_{gs}	Gate-Source Charge			27		nC
Q_{gd}	Gate-Drain Charge			48		nC

Drain-Source Diode Characteristics and Maximum Ratings

I _S	Maximum Continuous Drain–Source Diode Forward Current (Note 1)				80	A
I _{SM}	Maximum Pulsed Drain–Source Diode Forward Current (Note 1)				300	A
V _{SD}	Drain–Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 80 A (Note 1)		1	1.3	V

Notes:

1. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

Typical Characteristics

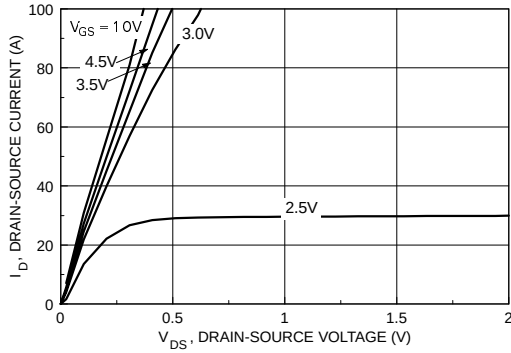


Figure 1. On-Region Characteristics.

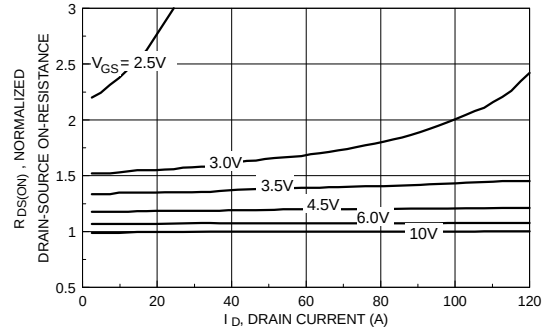


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

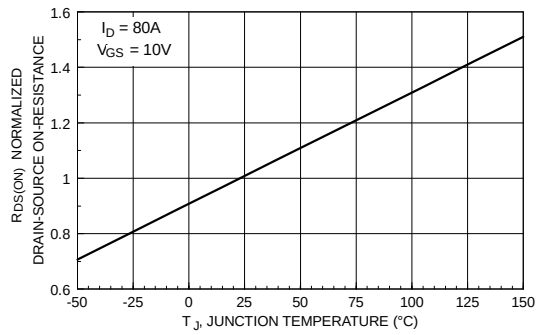


Figure 3. On-Resistance Variation with Temperature.

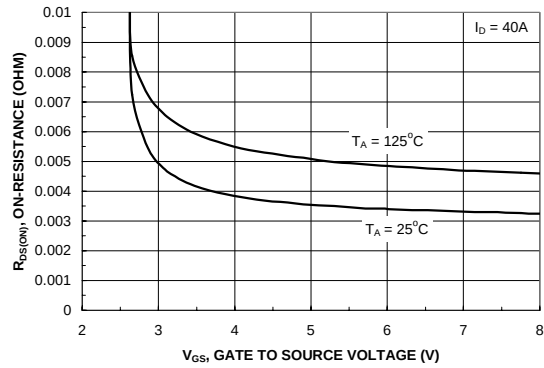


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

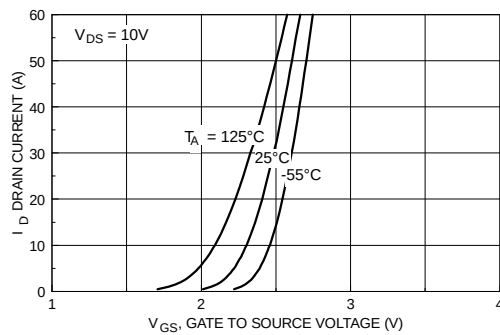


Figure 5. Transfer Characteristics.

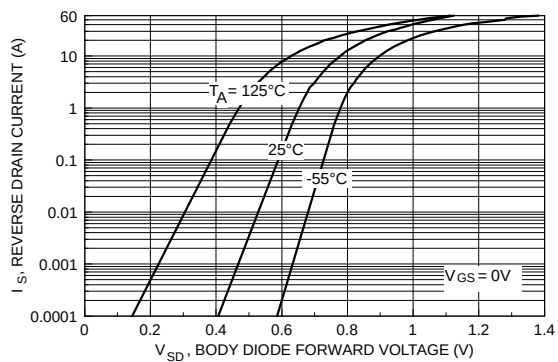


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics

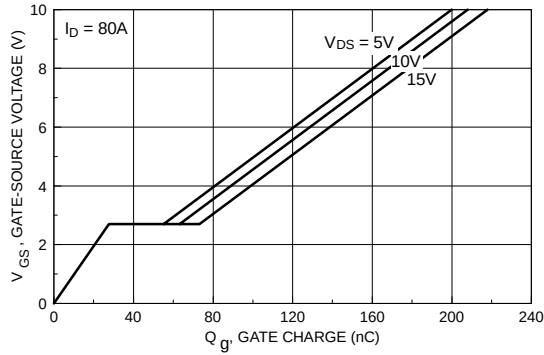


Figure 7. Gate Charge Characteristics.

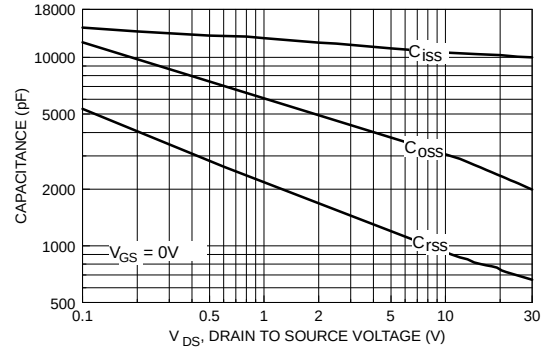


Figure 8. Capacitance Characteristics.

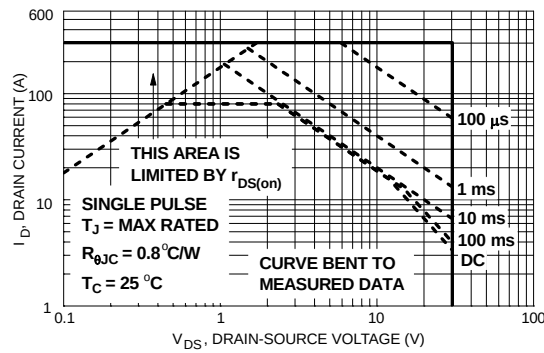


Figure 9. Maximum Safe Operating Area.

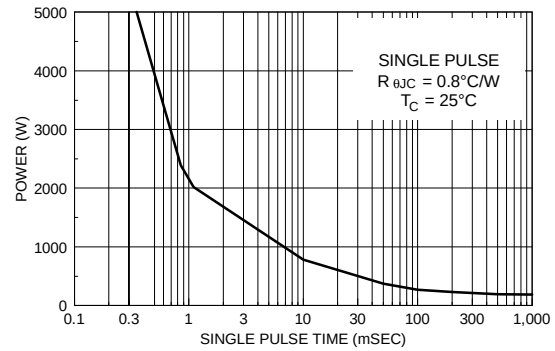


Figure 10. Single Pulse Maximum Power Dissipation.

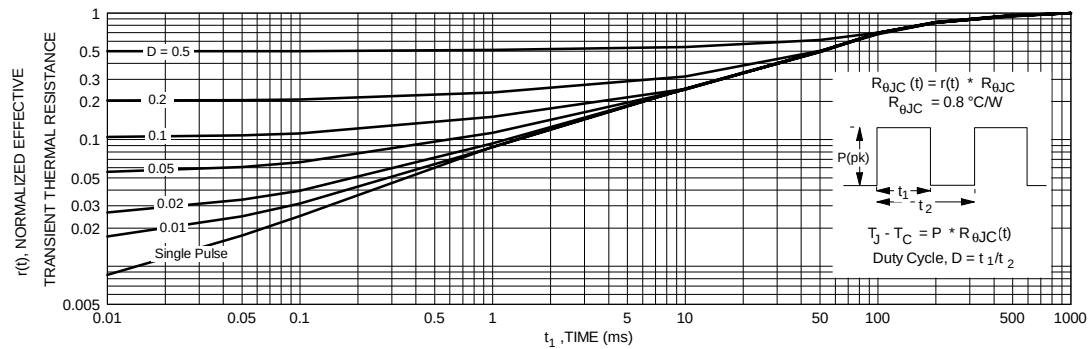


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1c.
Transient thermal response will change depending on the circuit board design.



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